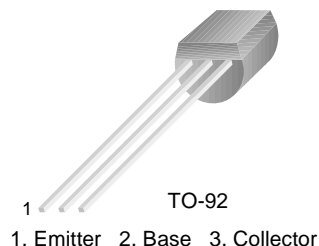


KSP42/43

KSP42/43

High Voltage Transistor

- Collector-Emitter Voltage: V_{CEO} =KSP42: 300V
KSP43: 200V
- Collector Power Dissipation: $P_C(\max)$ =625mW



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CBO}	Collector Base Voltage : KSP42 : KSP43	300 200	V V
V_{CEO}	Collector-Emitter Voltage : KSP42 : KSP43	300 200	V V
V_{EBO}	Emitter-Base Voltage	6	V
I_C	Collector Current	500	mA
P_C	Collector Power Dissipation	625	mW
T_J	Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage : KSP42 : KSP43	$I_C=100\mu\text{A}$, $I_E=0$	300 200		V V
BV_{CEO}	* Collector -Emitter Breakdown Voltage : KSP42 : KSP43	$I_C=1\text{mA}$, $I_B=0$	300 200		V V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_E=100\mu\text{A}$, $I_C=0$	6		V
I_{CBO}	Collector Cut-off Current : KSP42 : KSP43	$V_{CB}=200\text{V}$, $I_E=0$ $V_{CB}=160\text{V}$, $I_E=0$		100 100	nA nA
I_{EBO}	Emitter Cut-off Current : KSP42 : KSP43	$V_{BE}=6\text{V}$, $I_C=0$ $V_{BE}=4\text{V}$, $I_C=0$		100 100	nA nA
h_{FE}	* DC Current Gain	$V_{CE}=10\text{V}$, $I_C=1\text{mA}$ $V_{CE}=10\text{V}$, $I_C=10\text{mA}$ $V_{CE}=10\text{V}$, $I_C=30\text{mA}$	25 40 40		
$V_{CE}(\text{sat})$	* Collector-Emitter Saturation Voltage	$I_C=20\text{mA}$, $I_B=2\text{mA}$		0.5	V
$V_{BE}(\text{sat})$	* Base-Emitter Saturation Voltage	$I_C=20\text{mA}$, $I_B=2\text{mA}$		0.9	V
C_{ob}	Output Capacitance : KSP42 : KSP43	$V_{CB}=20\text{V}$, $I_E=0$ $f=1\text{MHz}$		3 4	pF pF
f_T	Current Gain Bandwidth Product	$V_{CE}=20\text{V}$, $I_C=10\text{mA}$ $f=100\text{MHz}$	50		MHz

* Pulse Test: $PW \leq 300\mu\text{s}$, Duty Cycles $\leq 2\%$

Typical Characteristics

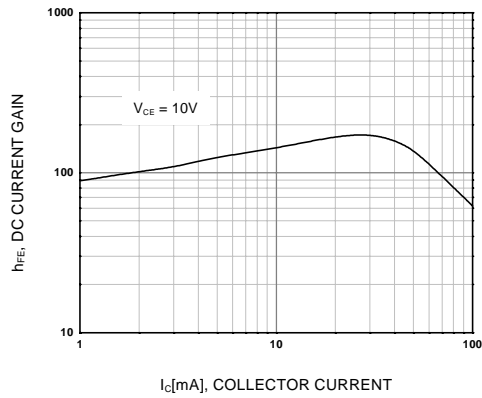


Figure 1. DC current Gain

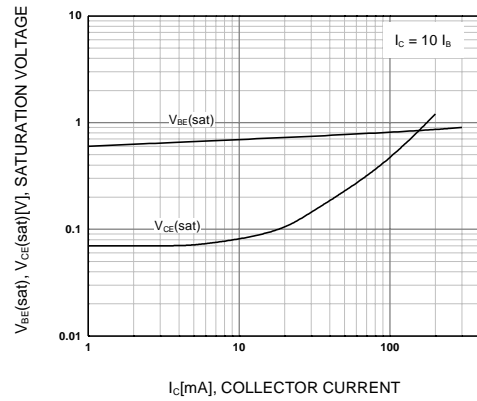


Figure 2. Collector-Emitter Saturation Voltage
Base-Emitter Saturation Voltage

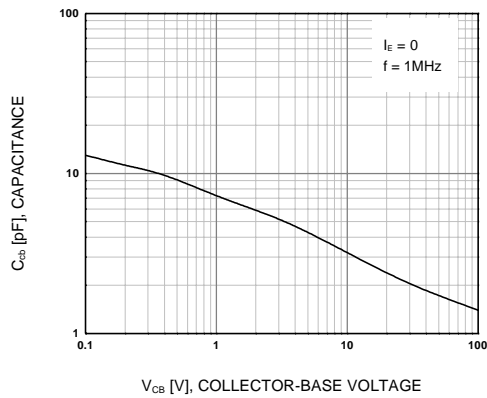


Figure 3. Collector-Base Capacitance

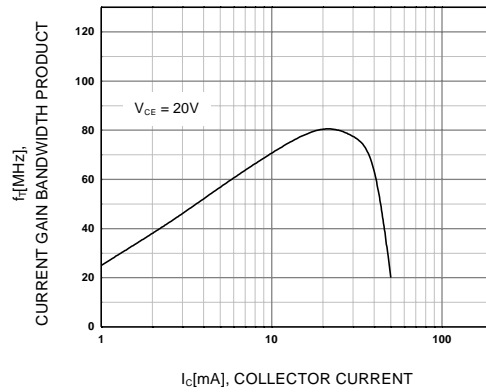


Figure 4. Current Gain Bandwidth Product

Package Dimensions

TO-92



Dimensions in Millimeters

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